# Quad 2-Input NAND Schmitt Trigger

## High–Performance Silicon–Gate CMOS

The MC74AC/74ACT132 contains four 2–input NAND gates which are capable of transforming slowly changing input signals into sharply defined, jitter–free output signals. In addition, they have greater noise margin than conventional NAND gates.

Each circuit contains a 2-input Schmitt trigger. The Schmitt trigger uses positive feedback to effectively speed-up slow input transitions, and provide different input threshold voltages for positive and negative-going transitions. This hysteresis between the positive-going and negative-going input threshold is determined by resistor ratios and is essentially insensitive to temperature and supply voltage variations.

### Features

- Schmitt Trigger Inputs
- Outputs Source/Sink 24 mA
- 'ACT132 Has TTL Compatible Inputs
- These are Pb–Free Devices

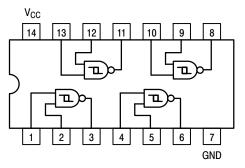


Figure 1. Pinout; 14–Lead Packages Conductors (Top View)

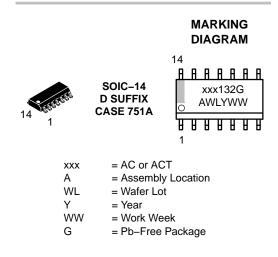
### FUNCTION TABLE

Inp	uts	Output
А	В	Ϋ
L	L	Н
L	Н	Н
Н	L	н
н	Н	L
H = HIGH V	oltage Level	L = LOW Voltage Level



### **ON Semiconductor®**

www.onsemi.com



### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

### MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V	
VI	DC Input Voltage	$-0.5 \leq V_{I} \leq V_{CC} + 0.5$	V	
Vo	DC Output Voltage (Note 1)	$-0.5 \le V_{O} \le V_{CC} + 0.5$	V	
I <sub>IK</sub>	DC Input Diode Current	±20	mA	
I <sub>OK</sub>	DC Output Diode Current	±50	mA	
I <sub>O</sub>	DC Output Sink/Source Current	±50	mA	
I <sub>CC</sub>	DC Supply Current per Output Pin	±50	mA	
I <sub>GND</sub>	DC Ground Current per Output Pin	±50	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
TL	Lead temperature, 1 mm from Case for 10 Seconds	260	°C	
TJ	Junction temperature under Bias	+ 150	°C	
$\theta_{JA}$	Thermal Resistance (Note 2)	125	°C/W	
P <sub>D</sub>	Power Dissipation in Still Air at 85°C	125	mW	
MSL	Moisture Sensitivity	Level 1		
F <sub>R</sub>	Flammability Rating Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in		
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 > 1000	V	
I <sub>Latch-Up</sub>	Latch–Up Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 6)	±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>O</sub> absolute maximum rating must be observed.

2. The package thermal impedance is calculated in accordance with JESD51-7.

3. Tested to EIA/JESD22-A114-A.

4. Tested to EIA/JESD22-A115-A.

5. Tested to JESD22-C101-A.

6. Tested to EIA/JESD78.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter			Тур	Max	Unit
N		′AC	2.0	5.0	6.0	N
V <sub>CC</sub>	Supply Voltage	′ACT	4.5	5.0	5.5	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	-	150	_	
t <sub>r</sub> , t <sub>f</sub> Input Rise and Fall Time (Note 1)	Input Rise and Fall Time (Note 1) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	_	ns/V
		V <sub>CC</sub> @ 5.5 V	-	25	_	
	Input Rise and Fall Time (Note 2)	V <sub>CC</sub> @ 4.5 V	-	10	_	ns/V
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	-	8.0	_	ns/v
TJ	Junction Temperature (PDIP)		_	-	140	°C
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C
I <sub>OH</sub>	Output Current – High		-	-	-24	mA
I <sub>OL</sub>	Output Current – Low		_	_	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1.  $V_{in}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 2.  $V_{in}$  from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

### **DC CHARACTERISTICS**

			74	74AC 74AC				
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = –40°C to +85°C	Unit	Conditions	
			Тур	Guar	anteed Limits			
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I <sub>OUT</sub> = –50 μA	
		3.0 4.5 5.5	- - -	2.56 3.86 4.86	2.46 3.76 4.76	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ -12 mA $I_{OH}$ -24 mA -24 mA	
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I <sub>OUT</sub> = 50 μA	
		3.0 4.5 5.5	- - -	0.36 0.36 0.36	0.44 0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $12 \text{ mA}$ $I_{OL}$ $24 \text{ mA}$ $24 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$	
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
ICC	Maximum Quiescent Supply Current	5.5	-	4.0	40	μΑ	$V_{IN} = V_{CC}$ or GND	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

### **AC CHARACTERISTICS**

			74AC			74AC			
Symbol	Parameter	V <sub>CC</sub> * (V)			T <sub>A</sub> = - to +8 C <sub>L</sub> = 9	35°C	Unit	Fig. No.	
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	3.3 5.0	2.0 2.0	-	13.0 9.0	1.5 1.5	14.0 10.0	ns	3–5
t <sub>PHL</sub>	Propagation Delay	3.3 5.0	2.0 2.0		13.5 9.0	1.5 1.5	15.0 10.0	ns	3–5

\*Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

### **DC CHARACTERISTICS**

			74 <i>A</i>	СТ	74ACT		
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = –40°C to +85°C	Unit	Conditions
			Тур	Guar	anteed Limits		
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA
		4.5 5.5		3.86 4.86	3.76 4.76	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ -24 mA $V_{OH}$ -24 mA
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA $V_{OL}$ 24 mA
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	_	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	_	1.5	mA	$V_{I} = V_{CC} - 2.1 V$
I <sub>OLD</sub>	†Minimum Dynamic	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max
I <sub>OHD</sub>	Output Current	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	4.0	40	μΑ	$V_{IN} = V_{CC}$ or GND

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. \*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

#### **AC CHARACTERISTICS**

			74ACT		74ACT				
Symbol	Parameter	V <sub>CC</sub> * (V)	T <sub>A</sub> = +25°C C <sub>L</sub> = 50 pF		$ \begin{array}{c} T_{A}=+25^{\circ}C \\ C_{L}=50 \ pF \end{array} \begin{array}{c} T_{A}=-40^{\circ}C \\ to \ +85^{\circ}C \\ C_{L}=50 \ pF \end{array} $		to +85°C Unit		Fig. No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay	5.0	3.0	-	11.5	2.5	13.0	ns	3–6
t <sub>PHL</sub>	Propagation Delay	5.0	3.0	-	11.0	2.5	12.5	ns	3–5

\*Voltage Range 5.0 V is 5.0 V  $\pm$ 0.5 V.

Symbol	Parameter	V <sub>CC</sub> (V)	74AC	74ACT	Unit	Test Conditions
V <sub>t+</sub>	Maximum Positive Threshold	3.0 4.5 5.5	2.2 3.2 3.9	2.0	V	T <sub>A</sub> = Worst Case
V <sub>t -</sub>	Minimum Negative Threshold	3.0 4.5 5.5	0.5 0.9 1.1	0.8	V	T <sub>A</sub> = Worst Case
V <sub>h(max)</sub>	Maximum Hysteresis	3.0 4.5 5.5	1.2 1.4 1.6	1.2	V	T <sub>A</sub> = Worst Case
V <sub>h(min)</sub>	Minimum Hysteresis	3.0 4.5 5.5	0.3 0.4 0.5	0.4	V	T <sub>A</sub> = Worst Case

### **INPUT CHARACTERISTICS** (unless otherwise specified)

### CAPACITANCE

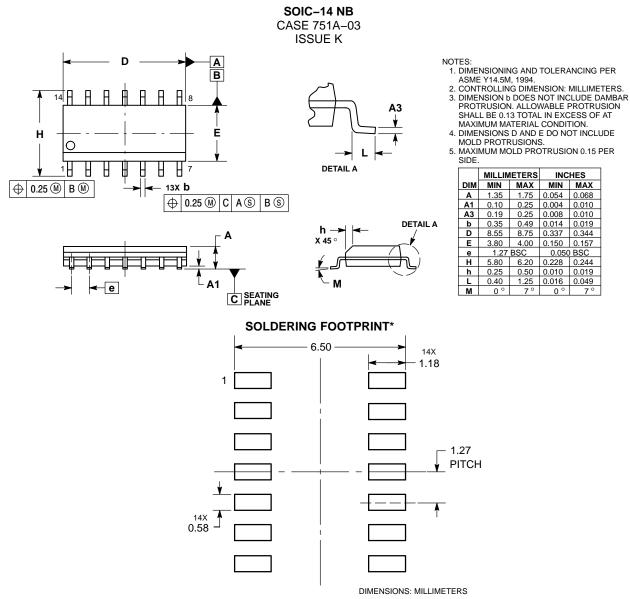
Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	30	pF	$V_{CC} = 5.0 V$

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MC74AC132DG	SOIC-14 (Pb-Free)	55 Units/Rail
MC74AC132DR2G	SOIC-14 (Pb-Free)	2500/Tape & Reel
MC74ACT132DG	SOIC-14 (Pb-Free)	55 Units/Rail
MC74ACT132DR2G	SOIC-14 (Pb-Free)	2500/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### PACKAGE DIMENSIONS



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the an are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC brows to rany such unintended or unauthorized application. Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81–3–5817–1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative